XPM82130E

17-V Input 3-A Step-Down Power Module with Integrated Inductor

FEATURES

- 3-mm × 2.8-mm × 1.4-mm LGA package
- 4.5-V to 17-V input range
- 3-A continuous output current
- Advanced CoT control topology
- FCCM mode for low ripple voltage
- 0.9-V to 6-V adjustable output voltage
- Power-good output
- Programmable soft start-up
- Thermal shutdown protection
- -55C to 125C operating temperature range
- EU RoHS compliance, Pb free

APPLICATIONS

- Industrial applications
- Telecom and networking applications
- Solid state drives

DESCRIPTION

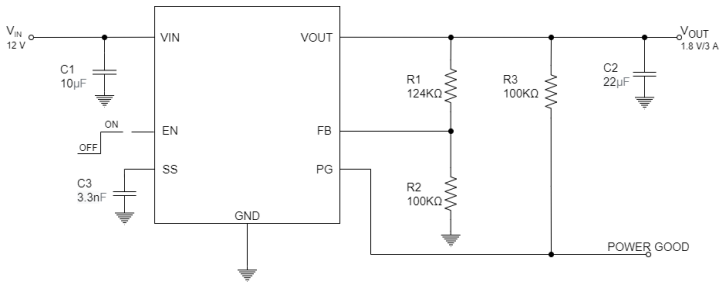
The XPM82130E is a 17-V input 3-A step-down power module optimized for small solution size and high efficiency. The module integrates a synchronous step-down converter and an inductor to simplify design, reduce external components, and save PCB area.

The low profile and compact solution is suitable for automated assembly by standard surface mount equipment.

The XPM82130E operates in PWM mode with a nominal 2MHz switching frequency across the whole load current range for low ripple voltage.

Using the Advanced CoT control topology, the XPM82130E achieves excellent load transient performance and accurate output voltage regulation.

TYPICAL APPLICATION



REVISION HISTORY

Release	Rev	Changes	Date
Released	0.9	Updates	3/15/2025

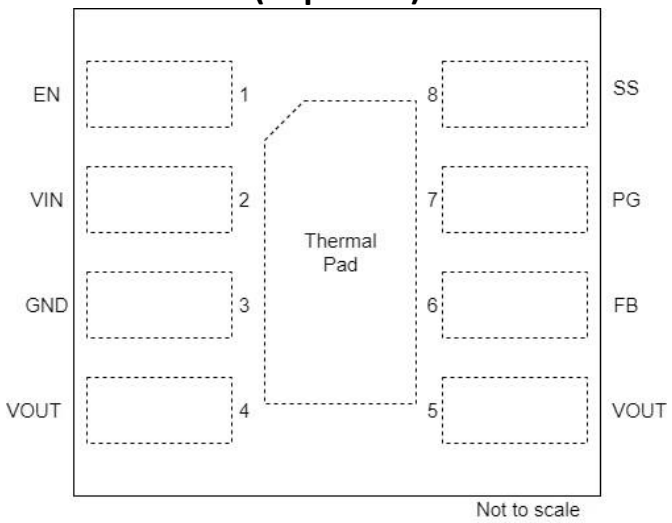
ORDERING INFORMATION

Part Number	Output Current (A)	VOUT (V)	Top Marking	MPQ
XPM82130E	3	Adjustable	Tracing code	3,000

MPQ = Minimum Packaging Quantity.
For production orders greater than MPQ, the order must be a multiple of MPQ per package size above.

PIN CONFIGURATION AND DESCRIPTION

8-Pin LGA Package
(Top View)



Pin Configuration

Pin	Name	Description
1	EN	Enable pin. Pull High to enable the device. Pull Low to disable the device. This pin has an internal pull-down resistor of typically 400 kΩ when the device is disabled.
2	VIN	Input pin.
3	GND	Ground pin.
4, 5	VOUT	Output pin.
6	FB	Feedback reference pin. An external resistor divider connected to this pin programs the output voltage.
7	PG	Power good open drain output pin. A pull up resistor can be connected to any voltage less than 6 V. Leave it open if it is not used.
8	SS	Soft startup pin. An external capacitor connected to this pin sets the internal reference voltage rising time.
	Exposed Thermal Pad	The exposed thermal pad must be connected to the GND pin. Must be soldered to achieve appropriate power dissipation and mechanical reliability.

ABSOLUTE MAXIMUM RATINGS

Parameter	Min	Max	Units
VIN	-0.3	20	V
EN, SS	-0.3	7	V
PG, FB	-0.3	7	V
VOUT	-0.3	7	V
Sink current at PG pin		10	mA
Module operating temperature	-55	+125	°C
Storage temperature	-55	+125	°C
Electrostatic Discharge (HBM)	-2000	+2000	V
Electrostatic Discharge (CDM)	-1000	+1000	V

(1) Operation of the device outside of these parameters may cause permanent damage.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Min	Typ	Max	Units
Input voltage	V_{IN}	4.5		17	V
Logic Interface (EN high)	V_{IH}	0.9		6	V
Logic Interface (EN Low)	V_{IL}	0		0.33	V
Power good pull-up resistor voltage	V_{PG}			6	V
Output voltage	V_{OUT}	0.9		6	V
Output current	I_{OUT}	0		3	A
Module operating temperature range	T_{OJ}	-40		110	°C

Thermal Information

Junction to ambient thermal resistance is a function of board layout and ambient air flow condition. This data is based on four layers PCB (30mm x 30mm; 70µm Cu top signal layer) in still air box in accordance with JEDEC standard JESD51 on natural convection.

Parameter	Symbol	Typ	Units
Junction-to-Ambient Thermal Resistance	θ_{JA}	50.2	°C/W
Junction-to-Case Thermal Resistance	θ_{JC}	8.6	°C/W

ELECTRICAL SPECIFICATIONS

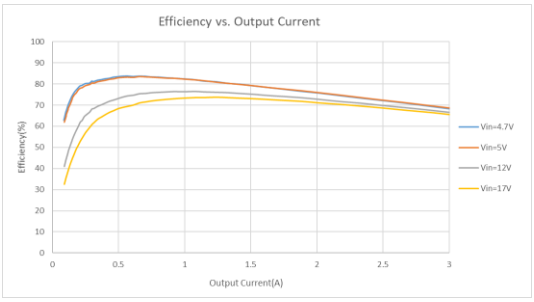
T_J = -55˚C to 125˚C and V_{IN} = 4.5V to 17V. Typical values are at T_J = 25°C and V_{IN} = 12V, unless otherwise noted.

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Supply						
Quiescent current into VIN	I_Q	No Load, device not switching		40		uA
Shutdown current into VIN	I_{SD}	EN = Low		1.5	7	uA
Undervoltage lockout threshold	V_{UVLO}	V_{IN} falling		3.8		V
		V_{IN} rising		4.2	4.5	V
Thermal shutdown threshold	T_{JSD}	T_J rising		160		°C
		T_J falling		140		°C
Logic Interface: EN						
High-level input voltage	V_{IH}		0.56	0.73	0.9	V
Low-level input voltage	V_{IL}		0.33	0.63	0.77	V
Input leakage current into EN pin	$I_{lkg(EN)}$	EN = High		0.01	1	µA
Control (SS, PG)						
SS pin source current	Iss			2.5		uA
Power good threshold	V_{PG}	V_{OUT} rising	92	95	99	%
		V_{OUT} falling	87	90	94	%
Power good low-level voltage	$V_{PG,OL}$	I_{sink} = 2mA		0.1	0.3	V
Input leakage current into PG Pin	$I_{lkg(PG)}$	V_{PG} = 1.8V			100	nA
Output						
Feedback regulation voltage	V_{FB}	PWM	785	800	815	mV
		PWM, TJ = 0°C to 85°C	790	800	810	mV
		PSM	785	800	823	mV
		PSM, TJ = 0°C to 85°C	788	800	812	mV
Feedback input leakage current	$I_{lkg(FB)}$	V_{FB} = 0.8 V		1	100	nA
Power Switch						
High-side FET on-resistance	R_{DSON}	V_{IN} ≥6V		85		mΩ
Low-side FET on-resistance		V_{IN} ≥6V		35		mΩ
Low-side FET switch current limit	I_{LIM}	V_{IN} = 6 V, T_A = 25°C	3	3.6	4.2	A
PWM switching frequency	f_{SW}	I_{OUT} = 1A, V_{OUT} = 1.8V		2		MHz

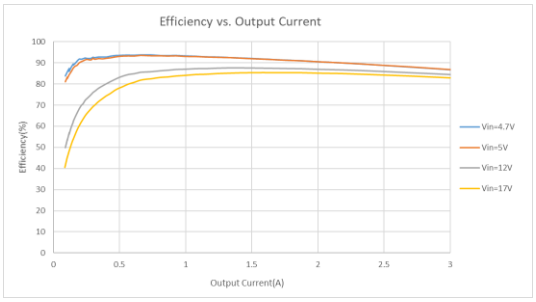
TYPICAL PERFORMANCE AND OPERATING CHARACTERISTICS

Test conditions unless otherwise noted: V_{IN} = 12V, V_{OUT} = 1.0V, C_{IN} = 2 x 10uF, C_{OUT} = 2 x 47uF and T_A = +25°C.

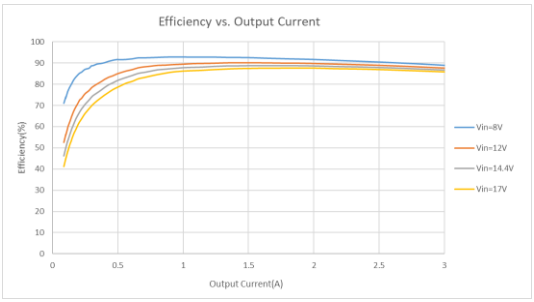
Efficiency vs. Load Current, V_{OUT} = 0.9V



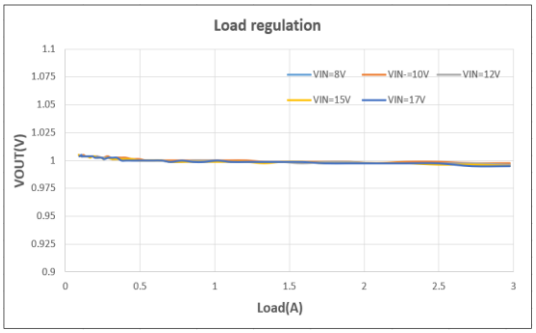
Efficiency vs. Load Current, V_{OUT} = 3.3V



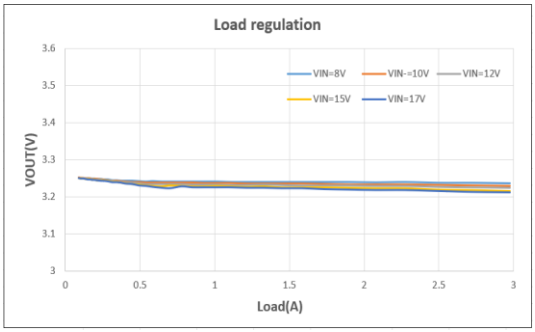
Efficiency vs. Load Current, V_{OUT} = 5V



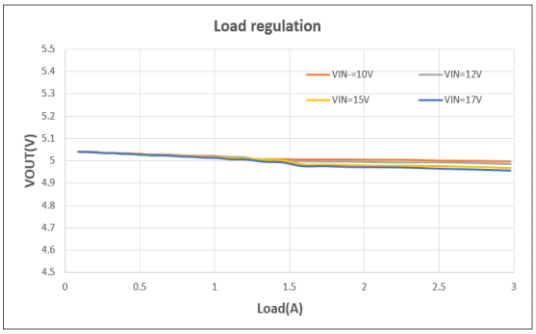
Load Regulation, V_{OUT} = 1.0V



Load Regulation, V_{OUT} = 3.25V



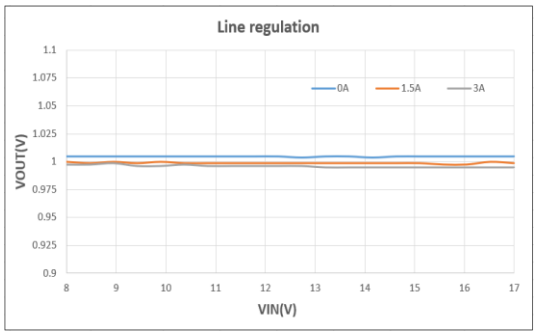
Load Regulation, V_{OUT} = 5.05V



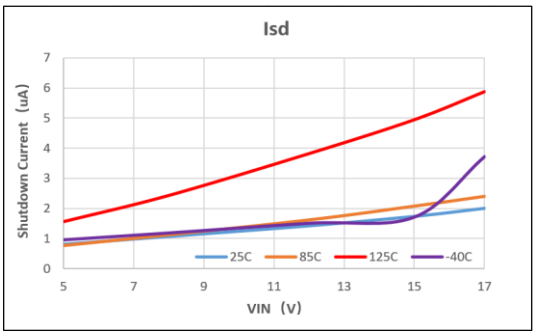
TYPICAL PERFORMANCE AND OPERATING CHARACTERISTICS

Test conditions unless otherwise noted: V_{IN} = 12V, V_{OUT} = 1.0V, C_{IN} = 2 x 10uF, C_{OUT} = 2 x 47uF and T_A = +25°C.
（continued）

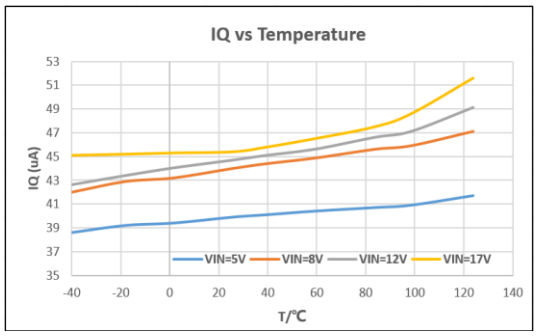
Line Regulation, V_{OUT} = 1.0V



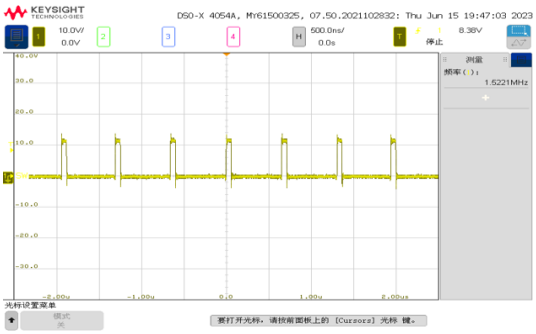
Shutdown Current



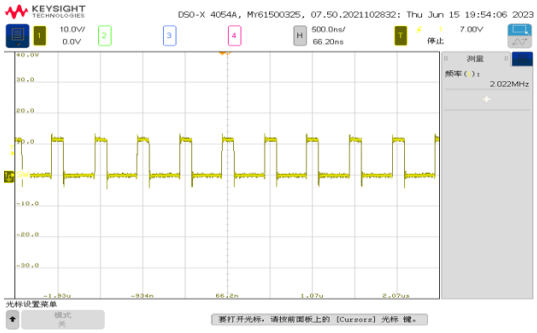
Quiescent Current



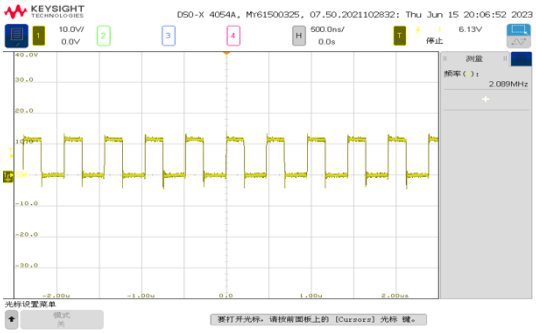
Switching Frequency, V_{OUT} = 1.0V, Load=3A



Switching Frequency, V_{OUT} = 3.3V, Load=3A



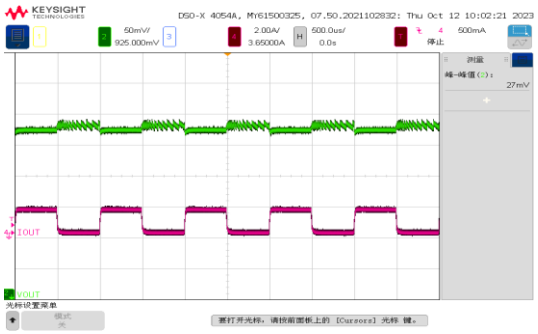
Switching Frequency, V_{OUT} = 5V, Load=3A



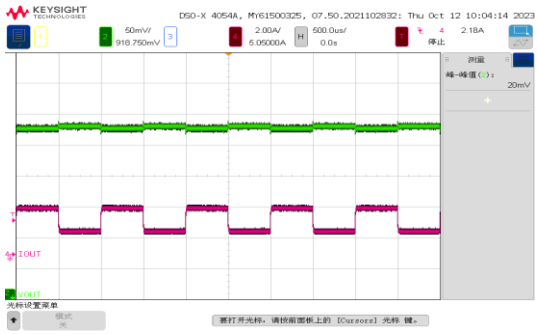
TYPICAL PERFORMANCE AND OPERATING CHARACTERISTICS

Test conditions unless otherwise noted: V_{IN} = 12V, V_{OUT} = 1.0V, C_{IN} = 2 x 10uF, C_{OUT} = 2 x 47uF and T_A = +25°C.
（continued）

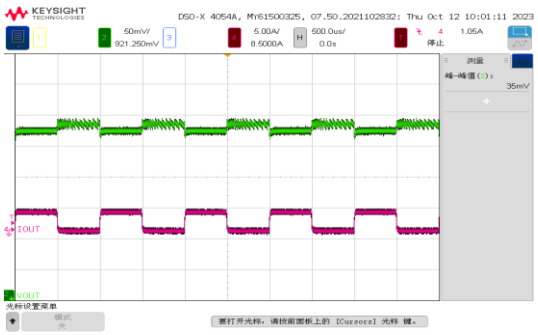
Load Transient, V_{OUT} = 1V, I_{LOAD} = 0A to 1.5A



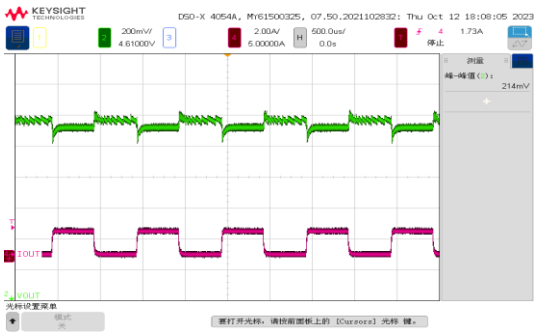
Load Transient, V_{OUT} = 1V, I_{LOAD} = 1.5A to 3A



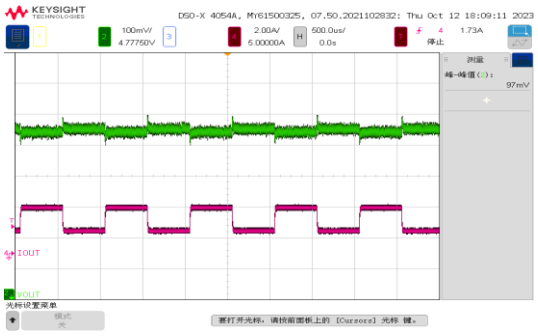
Load Transient, V_{OUT} =1V, I_{LOAD} = 0A to 3A



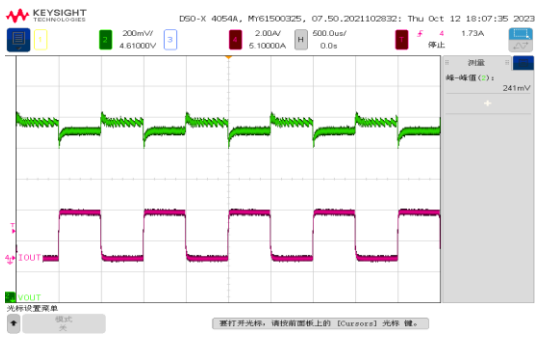
Load Transient, V_{OUT} = 5V, I_{LOAD} = 0A to 1.5A



Load Transient, V_{OUT} =5V, I_{LOAD} = 1.5A to 3A



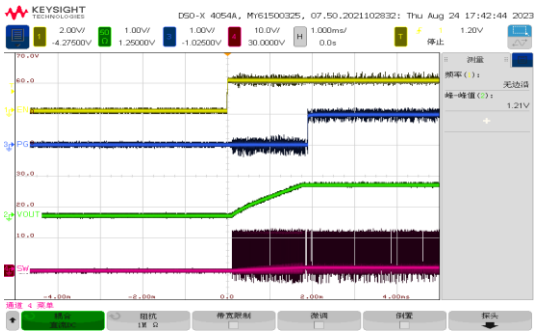
Load Transient, V_{OUT} =5V, I_{LOAD} = 0A to 3A



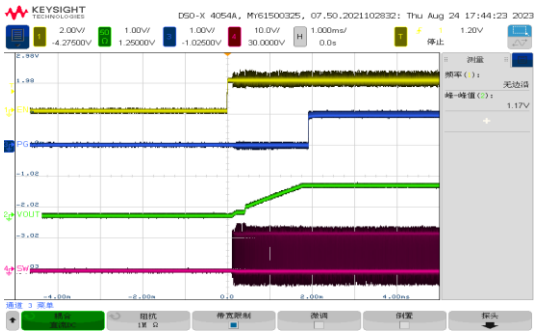
TYPICAL PERFORMANCE AND OPERATING CHARACTERISTICS

Test conditions unless otherwise noted: V_{IN} = 12V, V_{OUT} = 1.0V, C_{IN} = 2 x 10uF, C_{OUT} = 2 x 47uF and T_A = +25°C.
（continued）

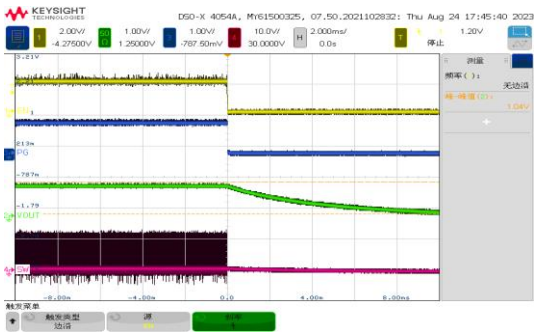
Start-Up Through Enable, V_{IN}=12V ,V_{OUT}=1.0V, I_{OUT}=0A



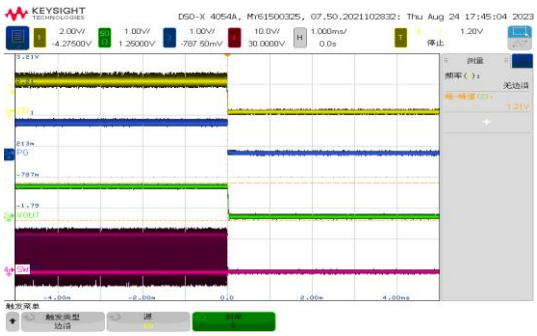
Start-Up Through Enable, V_{IN}=12V ,V_{OUT}=1.0V, I_{OUT}=3A



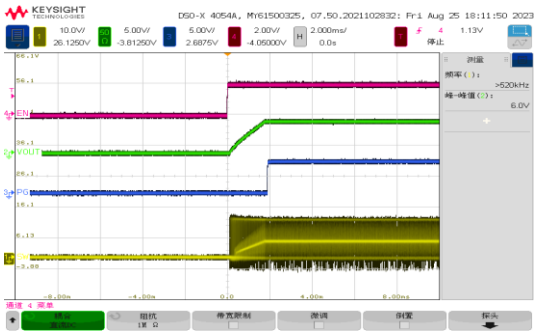
Shut down Through Enable , V_{IN}=12V ,V_{OUT}=1.0V,I_{OUT}=0A



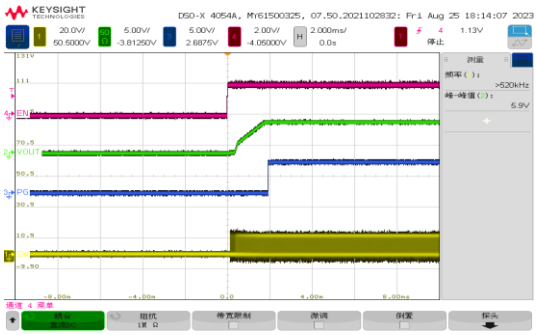
Shut down Through Enable , V_{IN}=12V ,V_{OUT}=1.0V, I_{OUT}=3A



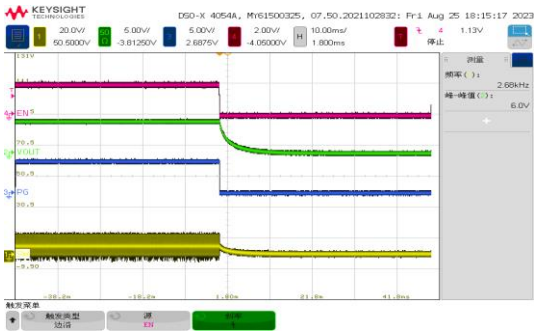
Start-Up Through Enable, V_{IN}=12V ,V_{OUT}=5V, I_{OUT}=0A



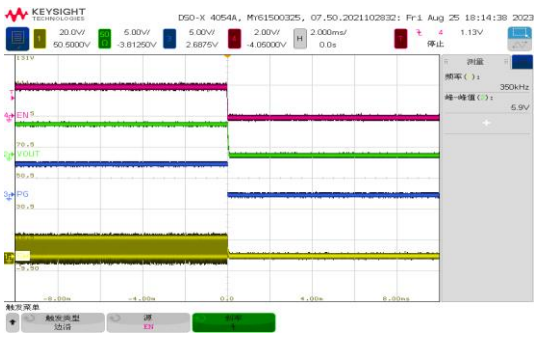
Start-Up Through Enable, V_{IN}=12V, V_{OUT}=5V, I_{OUT}=3A



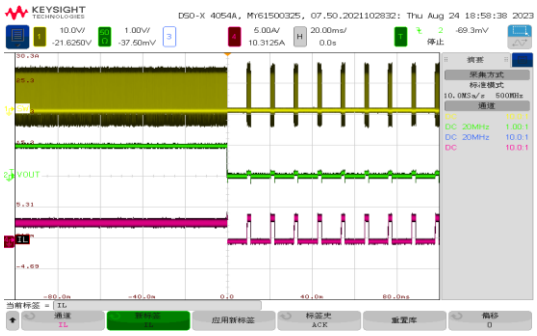
Shut down Through Enable, V_{IN}=12V, V_{OUT}=5V, I_{OUT}=0A



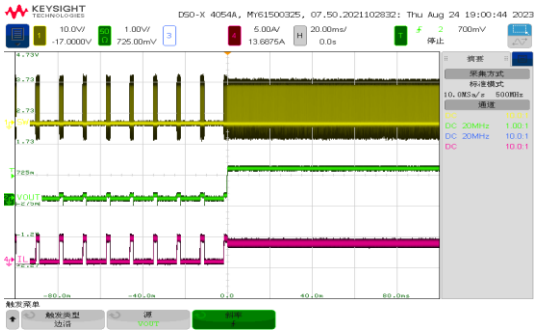
Shut down Through Enable, V_{IN}=12V ,V_{OUT}=5V, I_{OUT}=3A



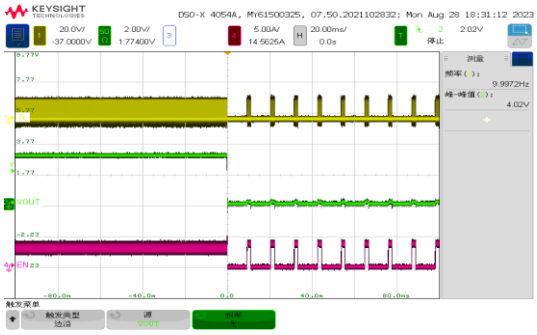
Short Circuit Protection, V_{IN}=12V, V_{OUT}=1.0V, 3A to Short



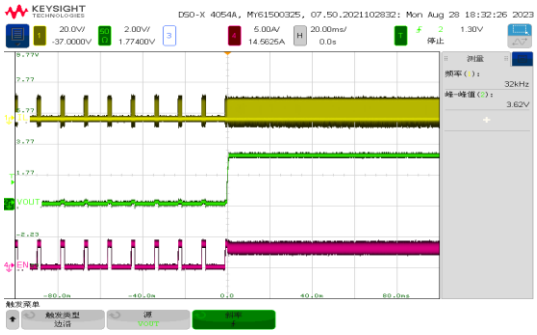
Short Circuit Recovery, V_{IN}=12V, V_{OUT}=1.0V, Short to 3A



Short Circuit Protection, V_{IN}=12V, V_{OUT}=3.3V, 3A to Short



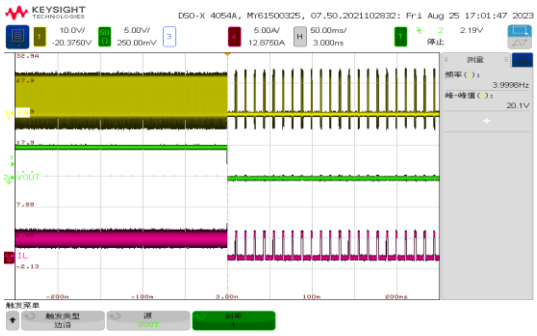
Short Circuit Recovery, V_{IN}=12V, V_{OUT}=3.3V, Short to 3A



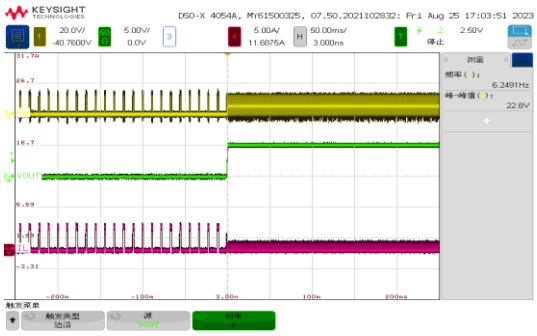
TYPICAL PERFORMANCE AND OPERATING CHARACTERISTICS

Test conditions unless otherwise noted: V_{IN} = 12V, V_{OUT} = 1.0V, C_{IN} = 2 x 10uF, C_{OUT} = 2 x 47uF and T_A = +25°C.
（continued）

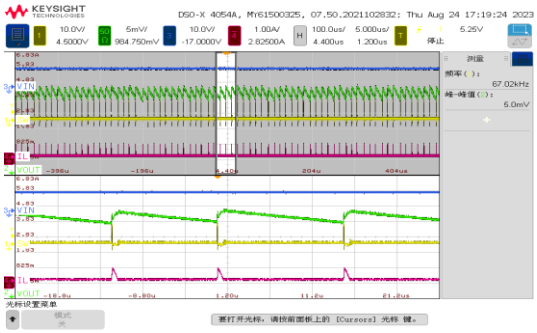
Short Circuit Protection, V_{IN}=12V, V_{OUT}=5V, 3A to Short



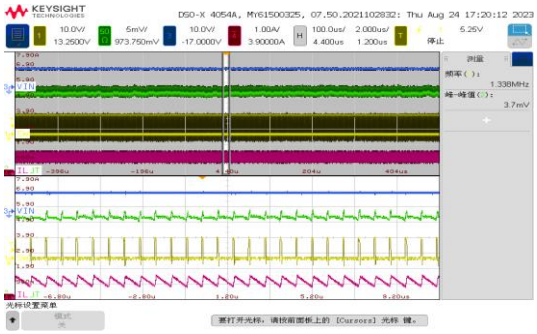
Short Circuit Recovery, V_{IN}=12V, V_{OUT}=5V, Short to 3A



Steady State Test, V_{IN}=12V, V_{OUT}=1.0V, Load=0A



Steady State Test, V_{IN}=12V, V_{OUT}=1.0V, Load=1A



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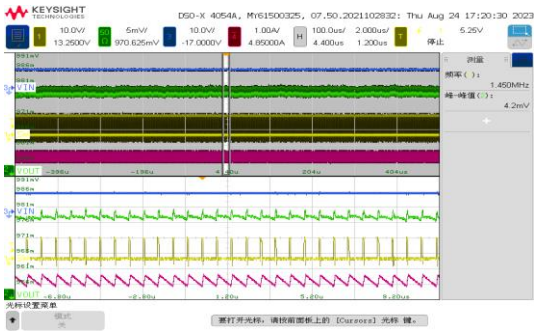
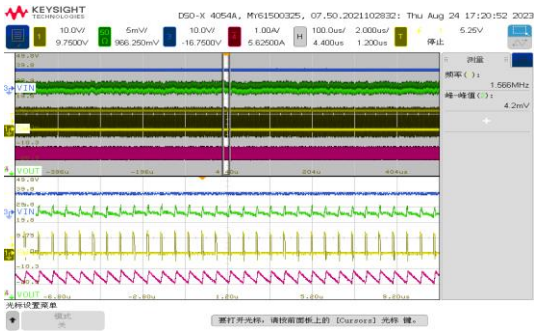
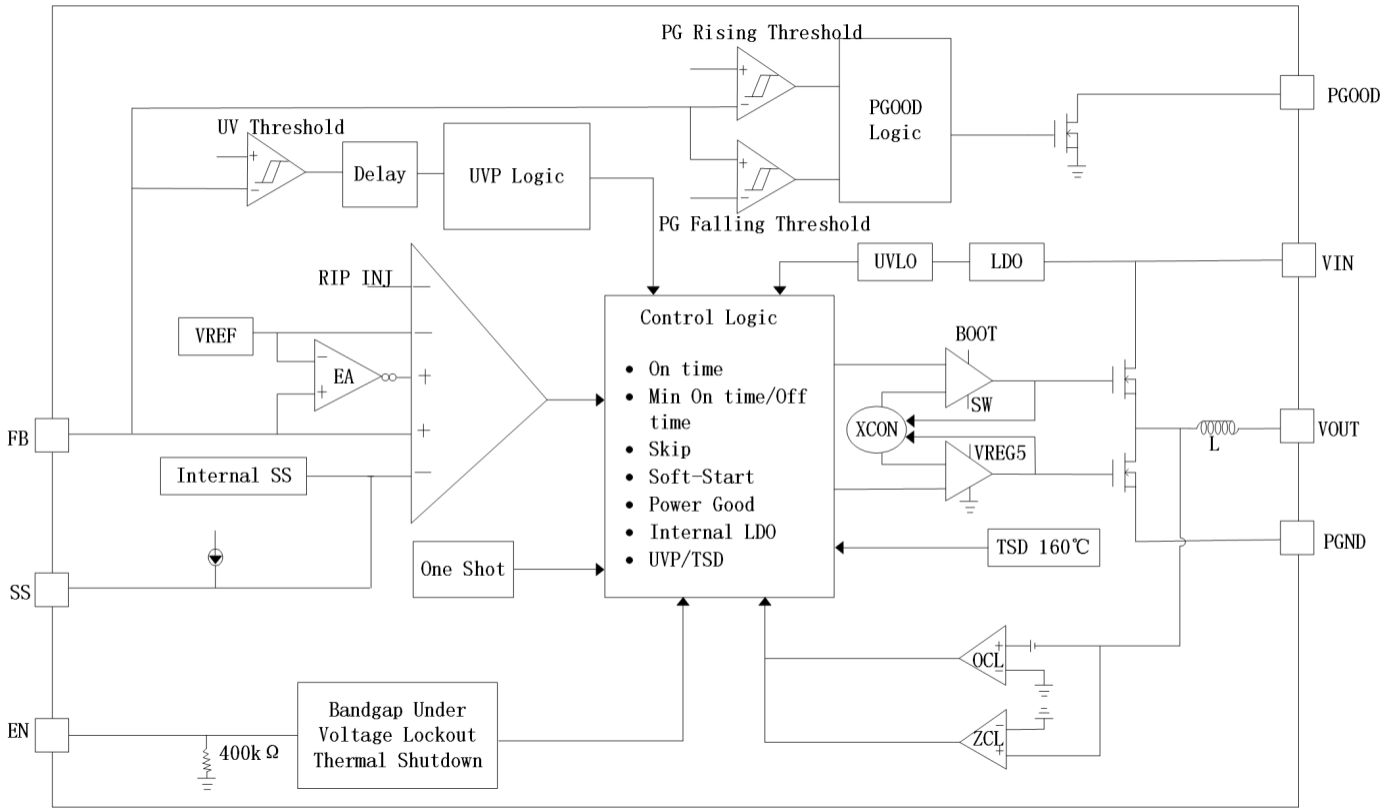


Steady State Test, V_{IN}=12V, V_{OUT}=1.0V, Load=3A



FUNCTIONAL DESCRIPTION



Block Diagram

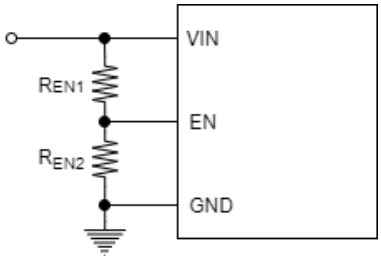
Overview

The XPM82130E is a synchronous step-down DC-DC voltage regulator available with switching frequency of 2MHz. Operating from an input voltage between 4.5V and 17V, the regulator can deliver up to 3A of load current.

Enable

Setting the EN pin to logic High enables the device. Alternatively, the device is disabled when the EN voltage is set to logic Low or floating. In this state the IC draws about 1.5μA of current.

The EN pin can also be applied to adjust XPM82130E Under-Voltage Lockout (UVLO) threshold with two external resistors divider from VIN to ground, please refer to the following graph for application structure.



Soft-Start

When the device is enabled, internal soft-start circuitry causes VOUT to ramp up over a period of 1ms to limit inrush current. This feature protects a high impedance source from being pulled to a lower voltage as the device turns on. The XPM82130E

is able to start into a pre-biased output capacitor. During the pre-biased start-up, both the power MOSFETs are not allowed to turn on until the internal voltage clamp sets an output voltage above the pre-bias voltage. When the device is in shutdown, under voltage lockout, or thermal shutdown, the capacitor connected to the SS pin is discharged by an internal resistor. Returning from those states causes a new start-up sequence.

A capacitance connected between the SS pin and the GND allows programming the start-up slope of the output voltage. A constant current of 2.5μA charges the external capacitor. The capacitance required for a given soft start-up time for the output voltage is given by: Css = Tss × Iss/1.25.

Under-voltage Lockout (UVLO)

The under-voltage lockout feature prevents the device from turning on if V_{IN} is below the UVLO level of 4.2V. If the device is enabled under UVLO conditions, the circuitry will not turn on until the input voltage is increased. Once active, the UVLO circuit has 400mV of hysteresis and the device will turn off if V_{IN} drops below 3.8V.

Thermal Shutdown

The device thermal shutdown protection is enabled if the chip temperature exceeds 160°C. Once the temperature drops below 140°C, the device will be re-enabled, and a new soft-start cycle will begin.

Over current Protection

The device has over current protection to prevent damage to the device and inductor during over current conditions.

Valley current protection occurs at 3.6A. After V_{OUT} drops to about 60%, the output will be disabled. After being disabled for 10ms, the device will be re-enabled, and a new soft-start cycle will begin.

Power Good Indicator

The PG pin is an open-drain output and pulls the PG pin low when the FB voltage is less than 90% of the nominal internal reference voltage and resumes when FB voltages is greater than 95% of the nominal internal reference voltage.

Power Good Pin Logic

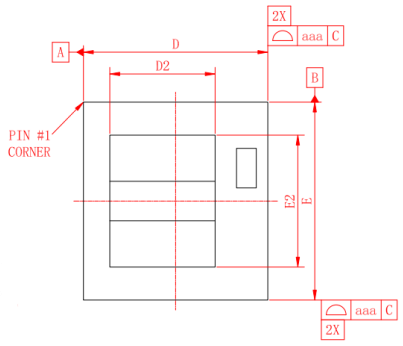
DEVICE STATE		PG LOGIC STATUS	
		HIGH IMPEDANCE	LOW
Enable (EN=High)	$V_{FB} \geq V_{TH\_PG}$	√	
	$V_{FB} \leq V_{TH\_PG}$		√
Shutdown (EN=Low)			√
UVLO	$0.7V < V_{IN} < V_{UVLO}$		√
Thermal Shutdown	$T_J > T_{SD}$		√
Power Supply Removal	$V_{IN} < 0.7V$	√	

XPM82130E

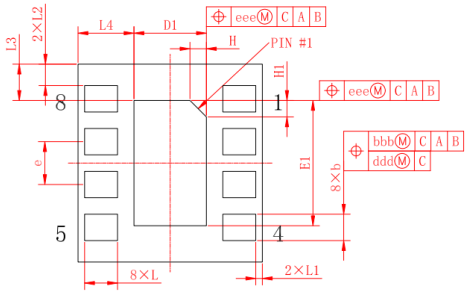
PHYSICAL DIMENSIONS

Table: Chip Dimensions

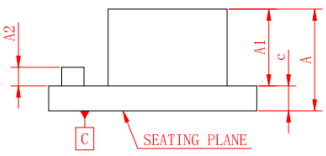
Symbol	Dimensions in mm		
	Min	Nom	Max
A	---	---	1.410
A1	---	---	1.040
A2	---	---	0.260
c	0.300	0.335	0.370
D	2.750	2.800	2.850
E	2.950	3.000	3.050
D1	1.000	1.100	1.200
E1	1.800	1.900	2.000
D2	1.400	1.600	1.800
E2	1.800	2.000	2.200
H	---	0.250	---
H1	---	0.250	---
L	0.450	0.500	0.550
L1	0.025	0.100	0.175
L2	0.250	0.325	0.400
L3	0.475	0.550	0.625
L4	0.775	0.850	0.925
e	---	0.650	---
b	0.350	0.400	0.450
aaa	0.100		
bbb	0.150		
ddd	0.080		
eee	0.150		



Top View



Bottom View



Side View